

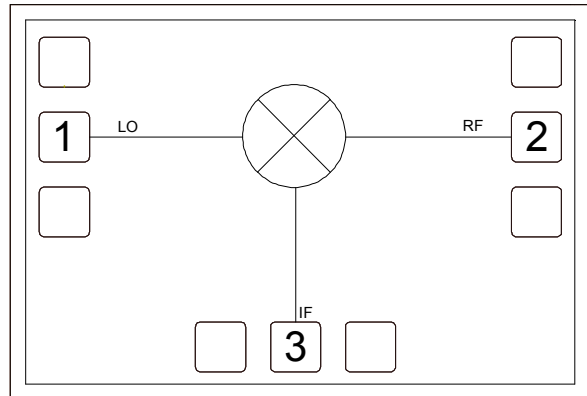
Features

- ▶ Low conversion loss
- ▶ High isolation
- ▶ Wide IF bandwidth
- ▶ Passive double balanced topology
- ▶ Small die size

Description

The CMD180 is a general purpose double balanced mixer die that can be used for up- and down converting applications between 20 and 32 GHz. The CMD180 has very high isolation to both the RF and IF ports due to the optimized balun structures, and can operate with an LO drive level as low as +9 dBm. The CMD180 can easily be configured as an image reject mixer or single sideband modulator with external hybrids and power splitters.

Functional Block Diagram



Electrical Performance – IF = 100 MHz, LO = +13 dBm , T_A = 25 °C, F = 26 GHz

Parameter	Min	Typ	Max	Units
Frequency Range, RF & LO	20 – 32			GHz
Frequency Range, IF	DC		10	GHz
Conversion Loss		7		dB
LO to RF Isolation		36		dB
LO to IF Isolation		36		dB
RF to IF Isolation		26		dB
Input P1dB		10		dBm

Unless otherwise noted, all measurements performed as a downconverter, IF = 100 MHz

Specifications

Absolute Maximum Ratings

Parameter	Rating
RF / IF Input Power	+21 dBm
LO Drive	+21 dBm
Operating Temperature	-55 to 85 °C
Storage Temperature	-55 to 150 °C
Thermal resistance, Θ_{JC}	672 °C / W
Power Dissipation, P _{diss}	96.7 mW

Exceeding any one or combination of the maximum ratings may cause permanent damage to the device.

Electrical Specifications – IF = 100 MHz, LO = +13 dBm, T_A = 25 °C

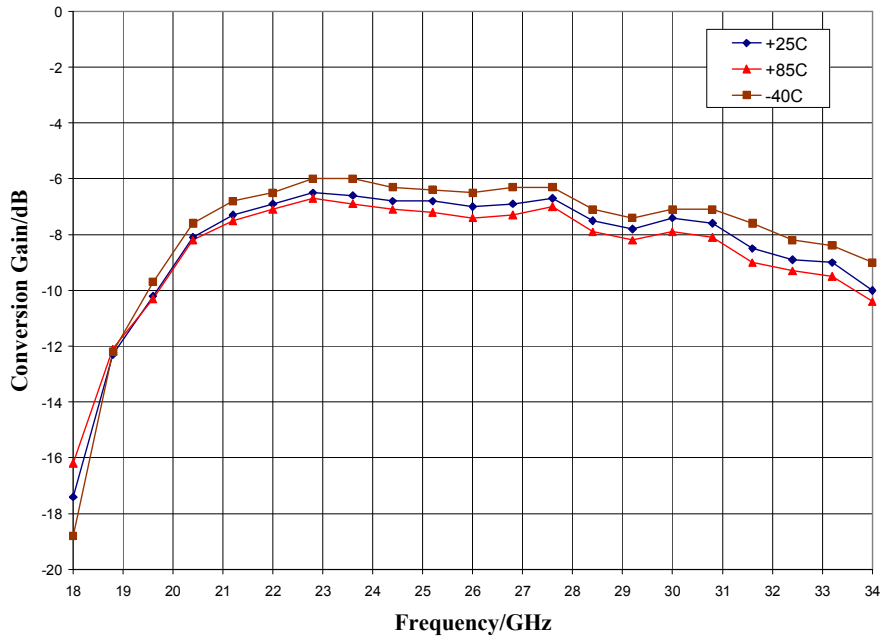
Parameter	Min	Typ	Max	Min	Typ	Max	Units
Frequency Range, RF & LO	22 – 28			20 – 32			GHz
Frequency Range, IF	DC		10	DC		10	GHz
Conversion Loss		7	9		7	11	dB
Noise Figure (SSB)		7	9		7	11	dB
LO to RF Isolation	31	36		27	36		dB
LO to IF Isolation	30	38		27	38		dB
RF to IF Isolation	19	26		16	26		dB
Input P _{1dB}		10			9		dBm
Input IP ₃		18			18		dBm

Unless otherwise noted, all measurements performed as a downconverter, IF = 100 MHz

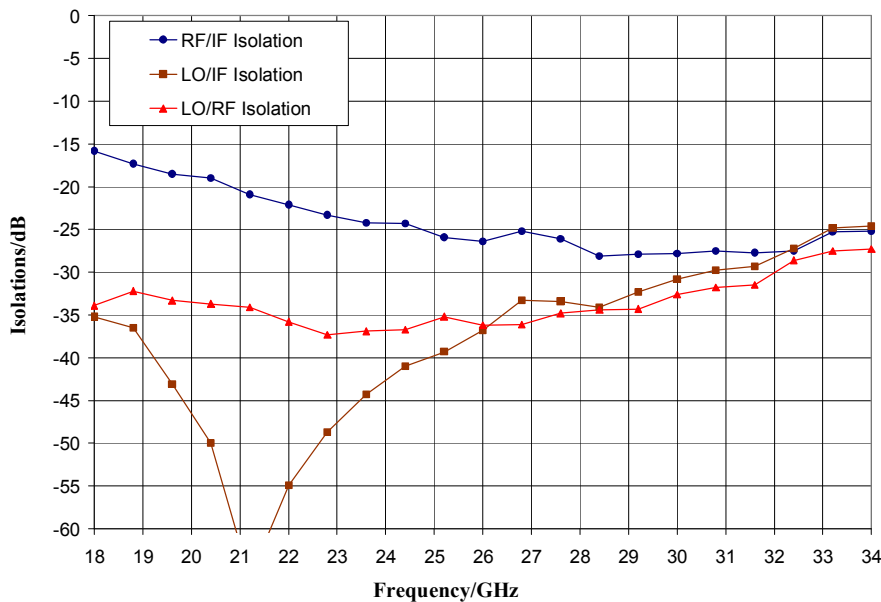
ver 1.2 0419

Typical Performance

Conversion Gain vs. Temperature, LO = +13 dBm, IF = 100 MHz USB

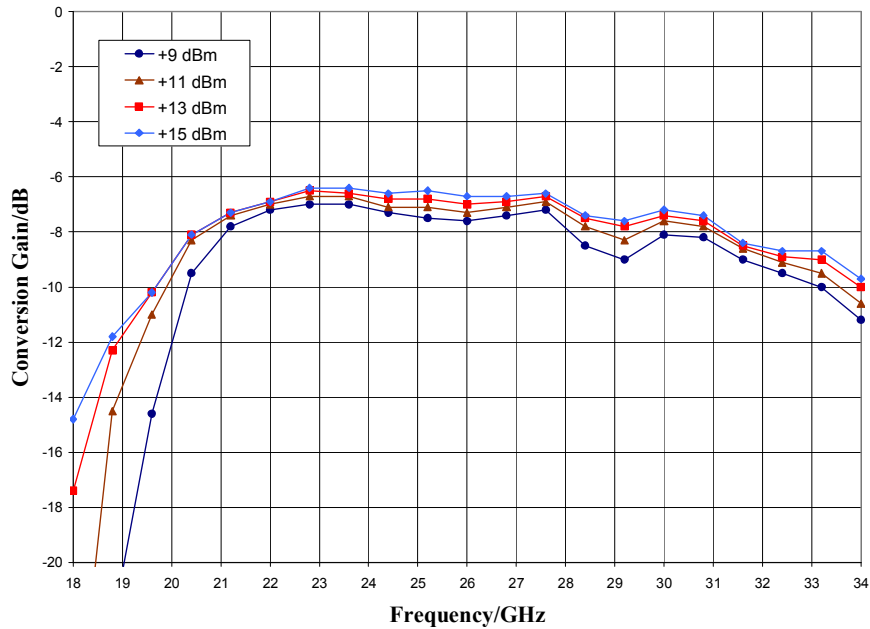


Isolation, LO = +13 dBm

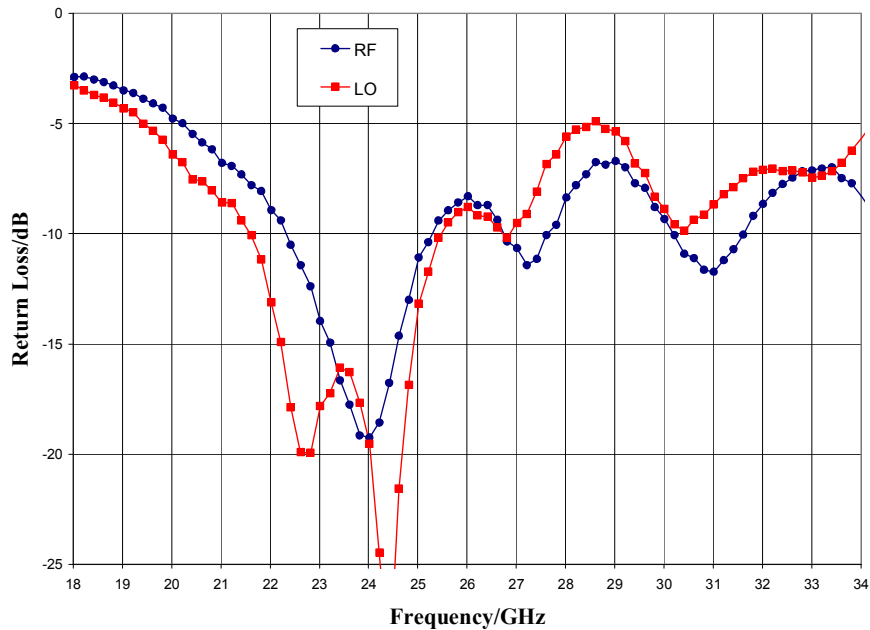


Typical Performance

Conversion Gain vs. LO Drive, IF = 100 MHz USB



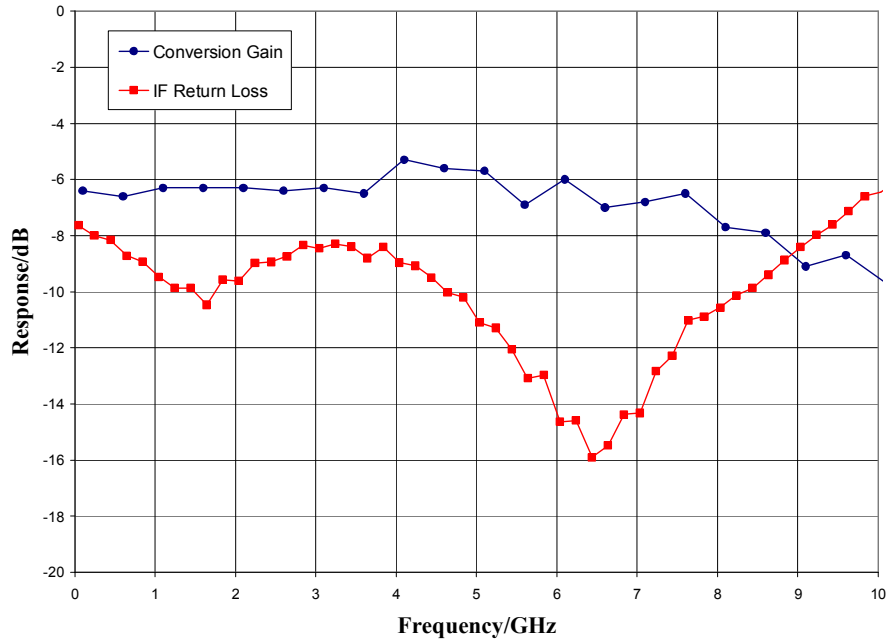
Return Loss, LO = + 13 dBm



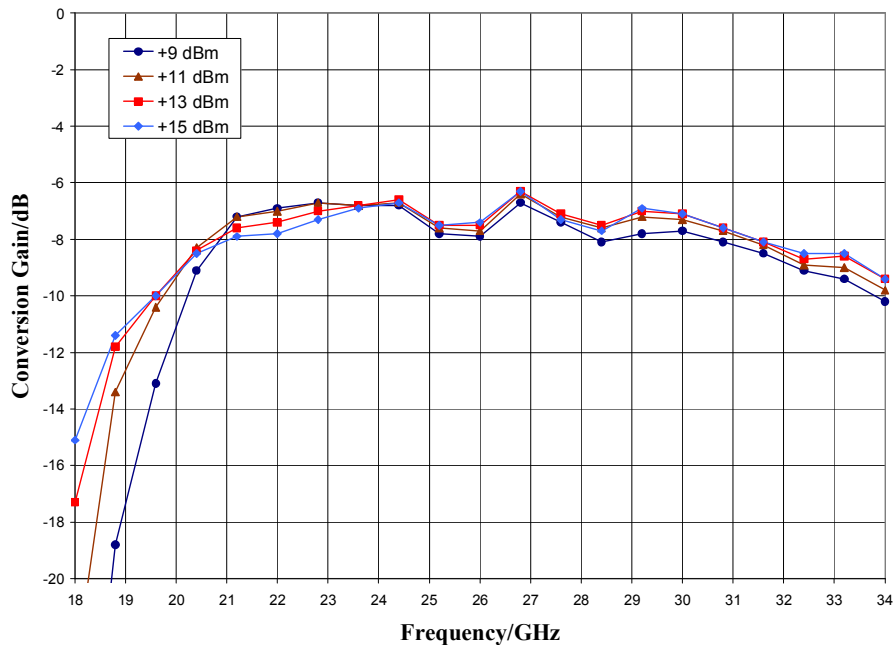
ver 1.2 0419

Typical Performance

IF Bandwidth, LO = +13 dBm



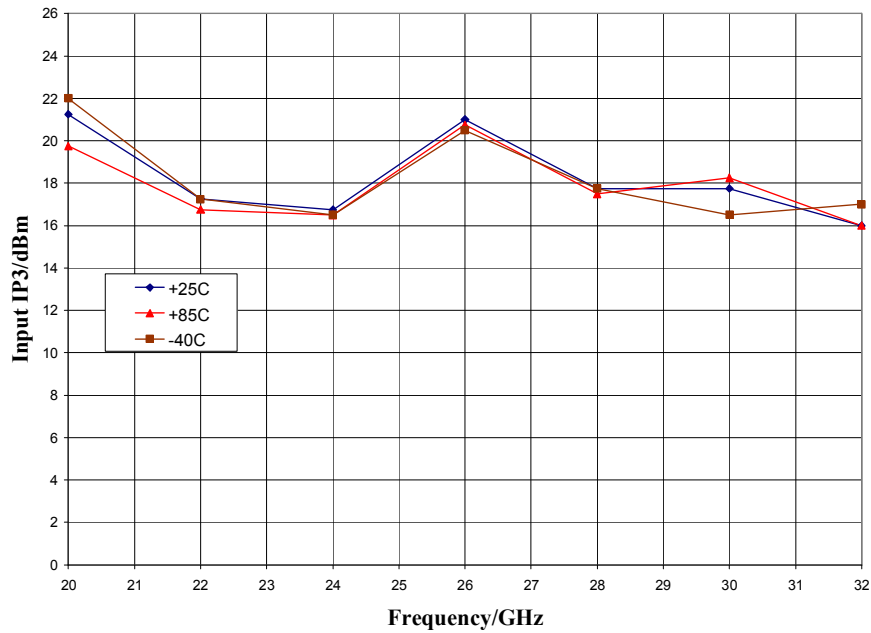
Upconverter Performance, Conversion Gain vs. LO Drive, IF input = 100 MHz



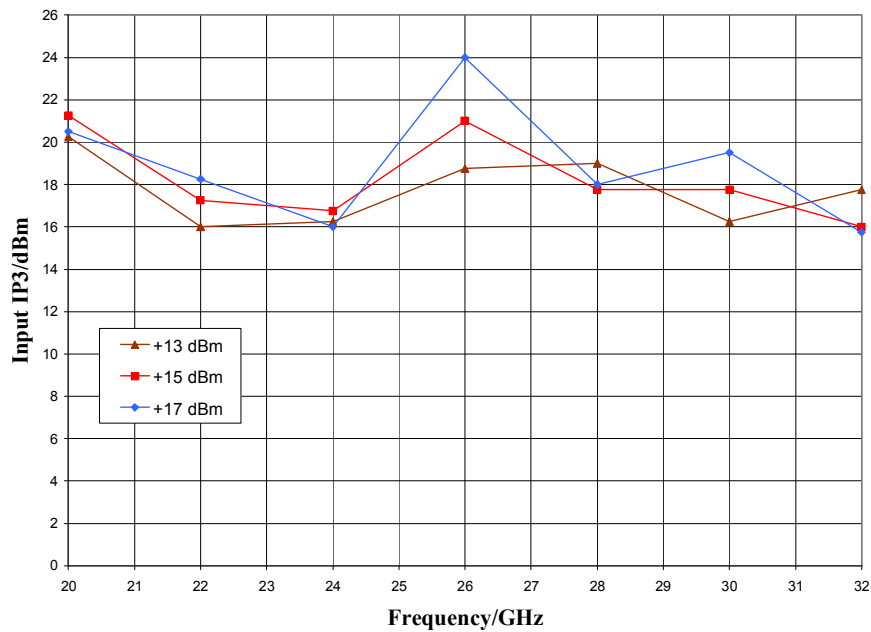
ver 1.2 0419

Typical Performance

Input IP3 vs. Temperature, LO = +15 dBm, IF = 100 MHz

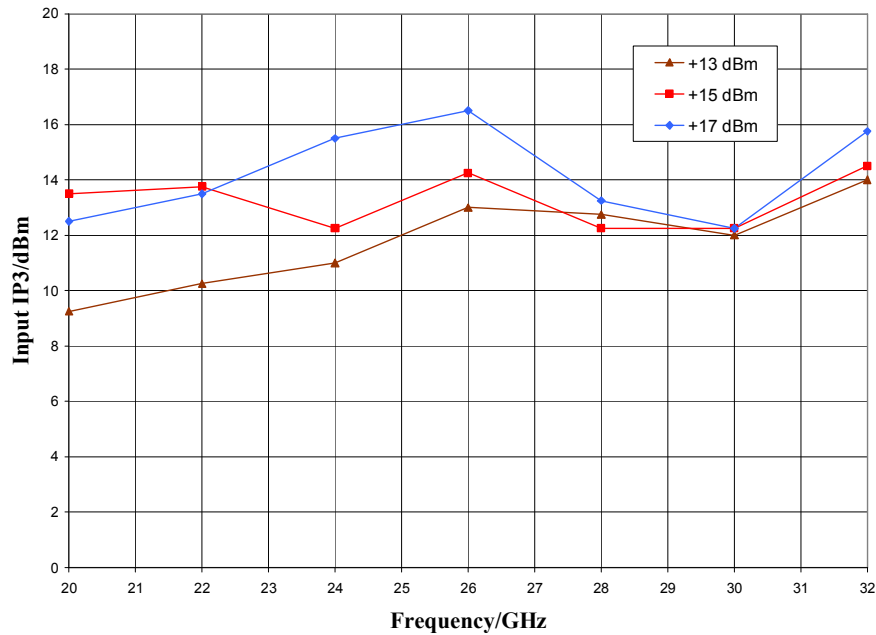


Input IP3 vs. LO Drive, IF = 100 MHz

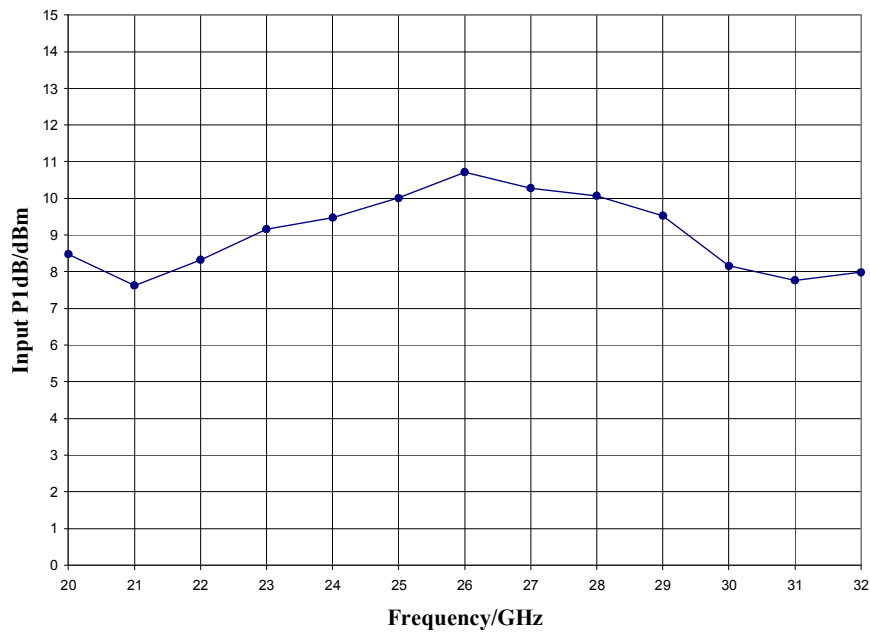


Typical Performance

Upconverter Performance, Input IP3 vs. LO Drive, IF = 100 MHz



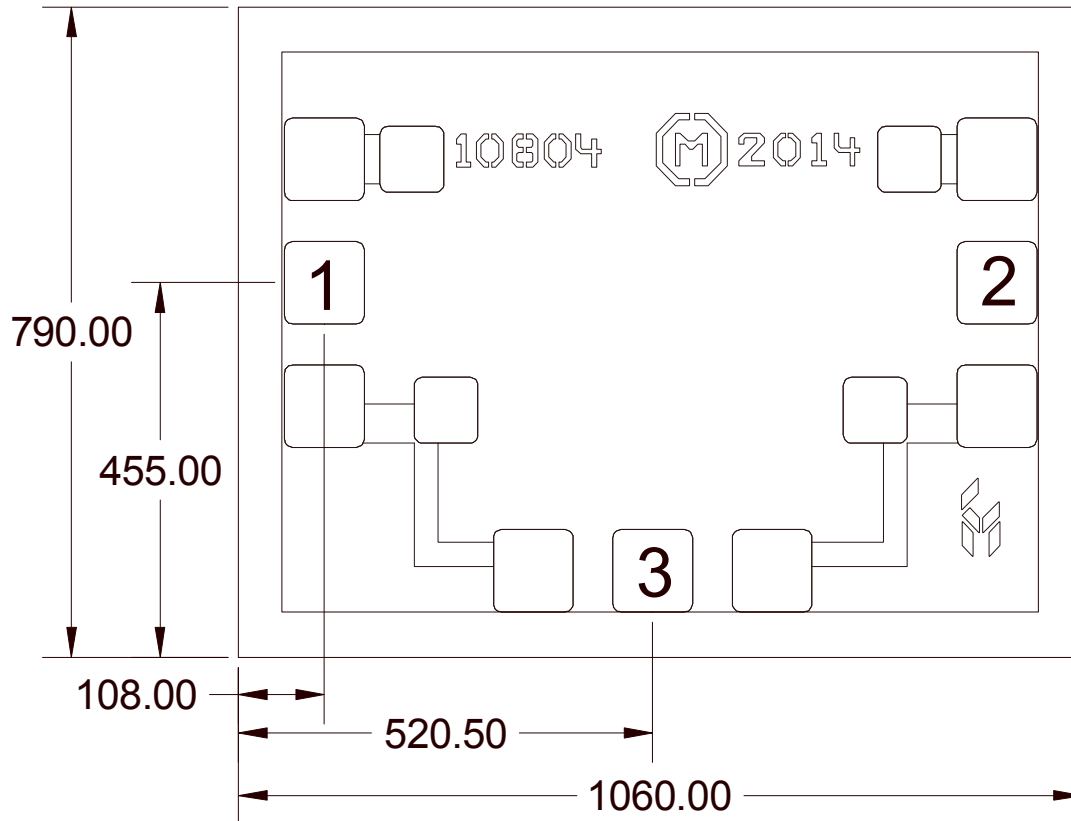
Input P1dB, LO = +13 dBm, IF = 100 MHz USB



ver 1.2 0419

Mechanical Information

Die Outline (all dimensions in microns)

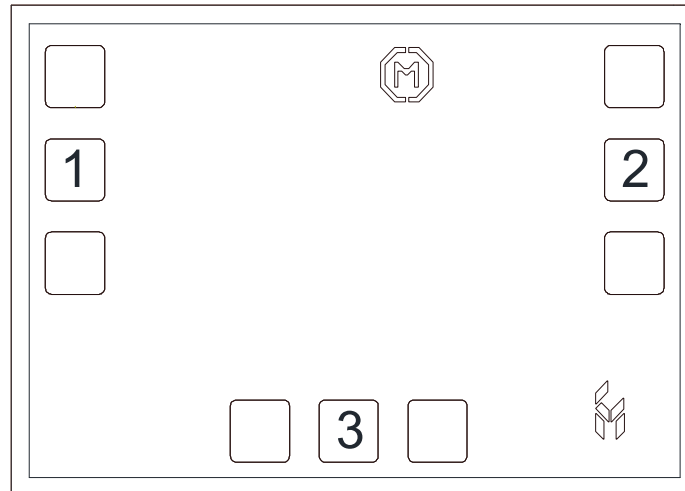


Notes:

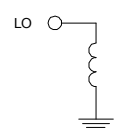
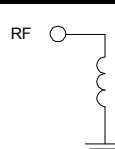
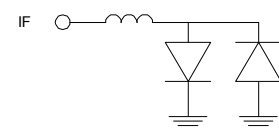

1. No connection required for unlabeled pads
2. Backside is RF and DC ground
3. Backside and bond pad metal: Gold
4. Die is 100 microns thick
5. All bond pads (1, 2, 3) are 100 x 100 microns

Pin Description

Pad Diagram



Functional Description

Pin	Function	Description	Schematic
1	LO	This pin is DC coupled and matched to 50 ohms.	
2	RF	This pin is DC coupled and matched to 50 ohms.	
3	IF	This pin is DC coupled. For applications not requiring operation to DC, this port should be DC blocked externally using a series capacitor whose value has been chosen to pass the necessary IF frequency range. For operation to DC, this pin must not source or sink more than 16 mA of current or part non-function or part failure may result.	
Backside	Ground	Connect to RF / DC ground.	

ver 1.2 0419